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Architecture and Method to design common PUF/TRNG functions

Cryptachi Workshop

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Jean-Luc DANGER

Prof. Télécom ParisTech

Scientific Advisor Secure-IC

**Joint work with Yves Mathieu, Prof. Télécom ParisTech
Thibault Portebeuf, project Leader Secure-IC**





Agenda

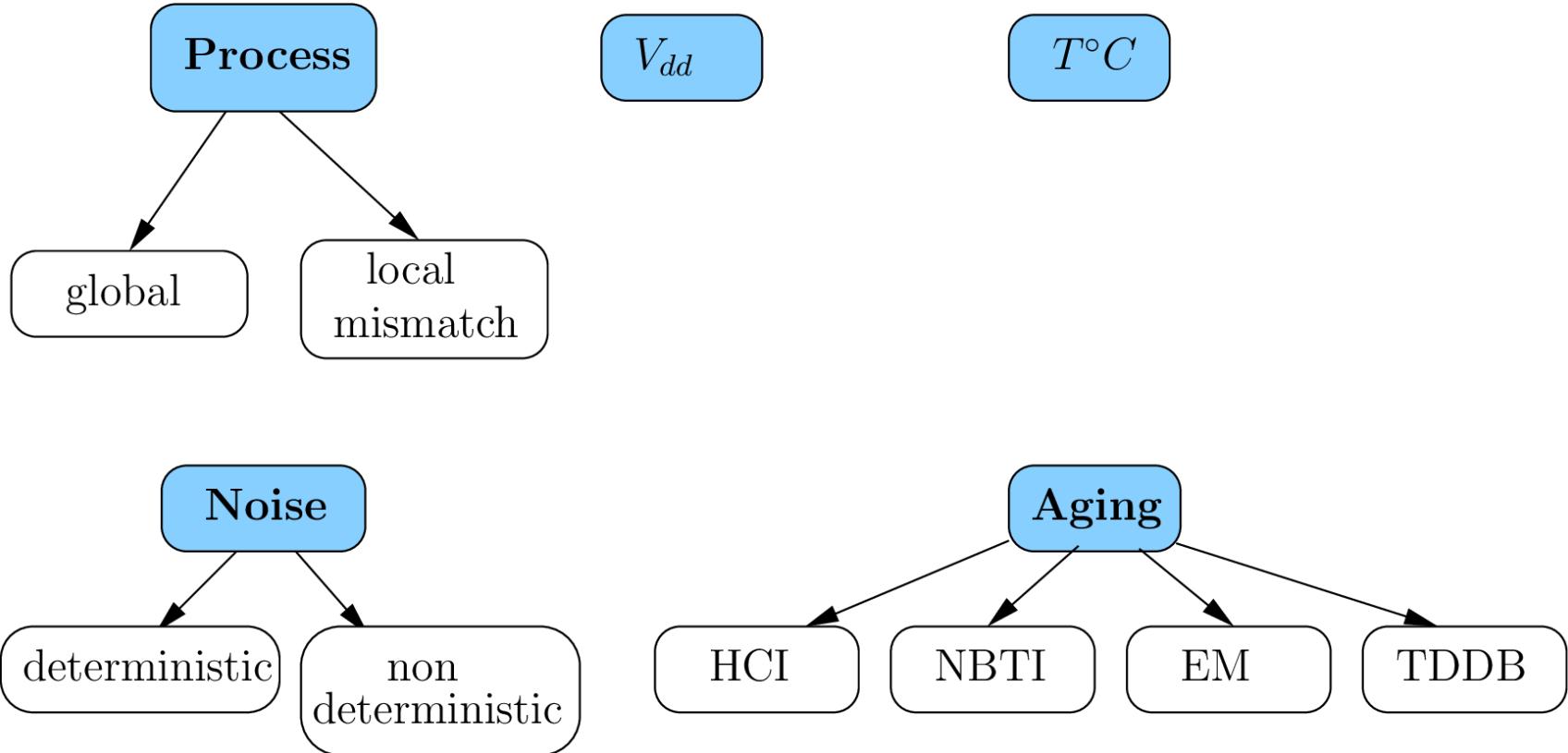
- IC Variability for PUF/TRNG
- Mixed PUF/TRNG concept
- Results
- Conclusions



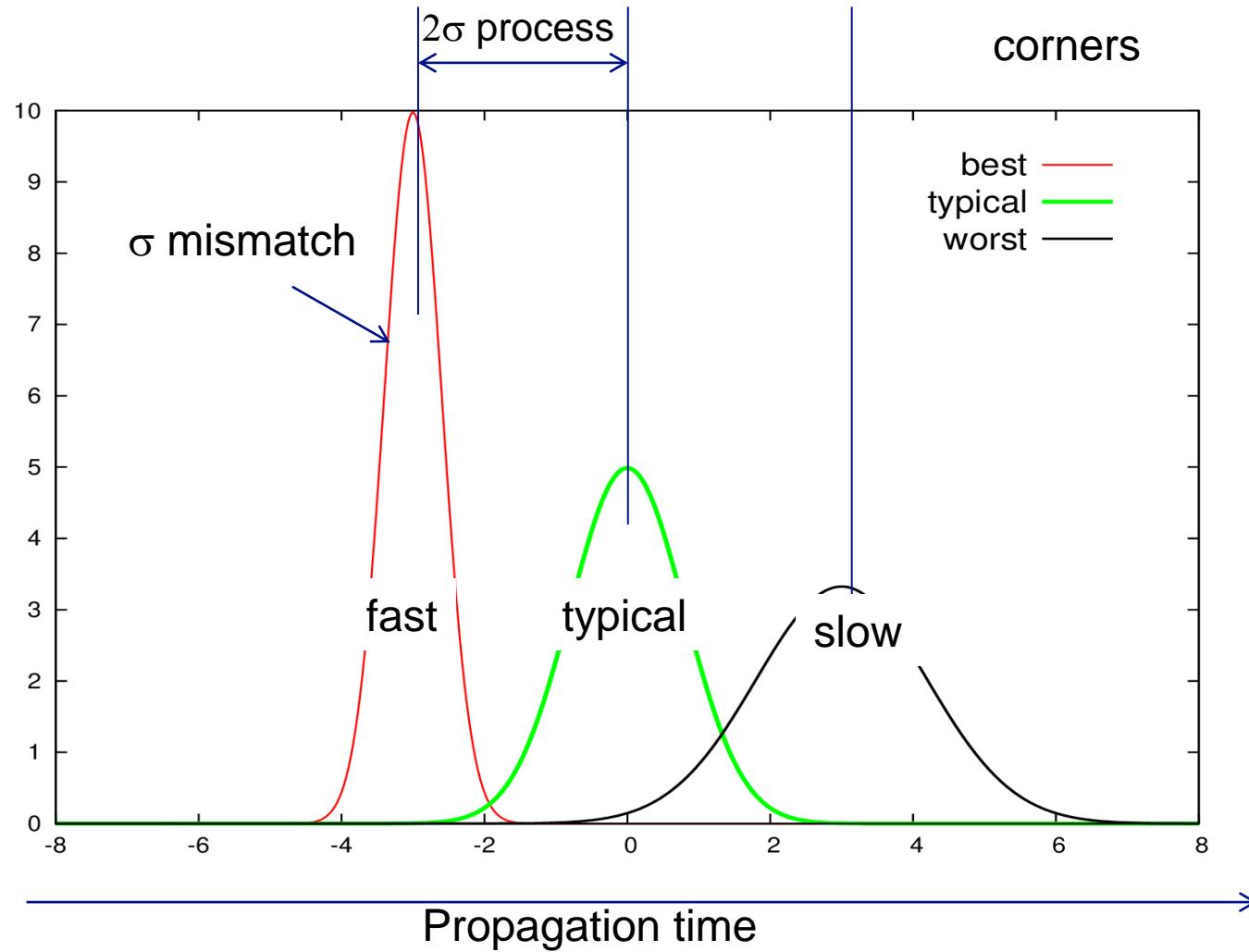
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Causes of IC Variability



Process dispersion





Noise

■ Sum of different phenomenon:

- Thermal noise
- 1/F noise
- Shot noise
- Popcorn noise
- Crosstalk
- Interference

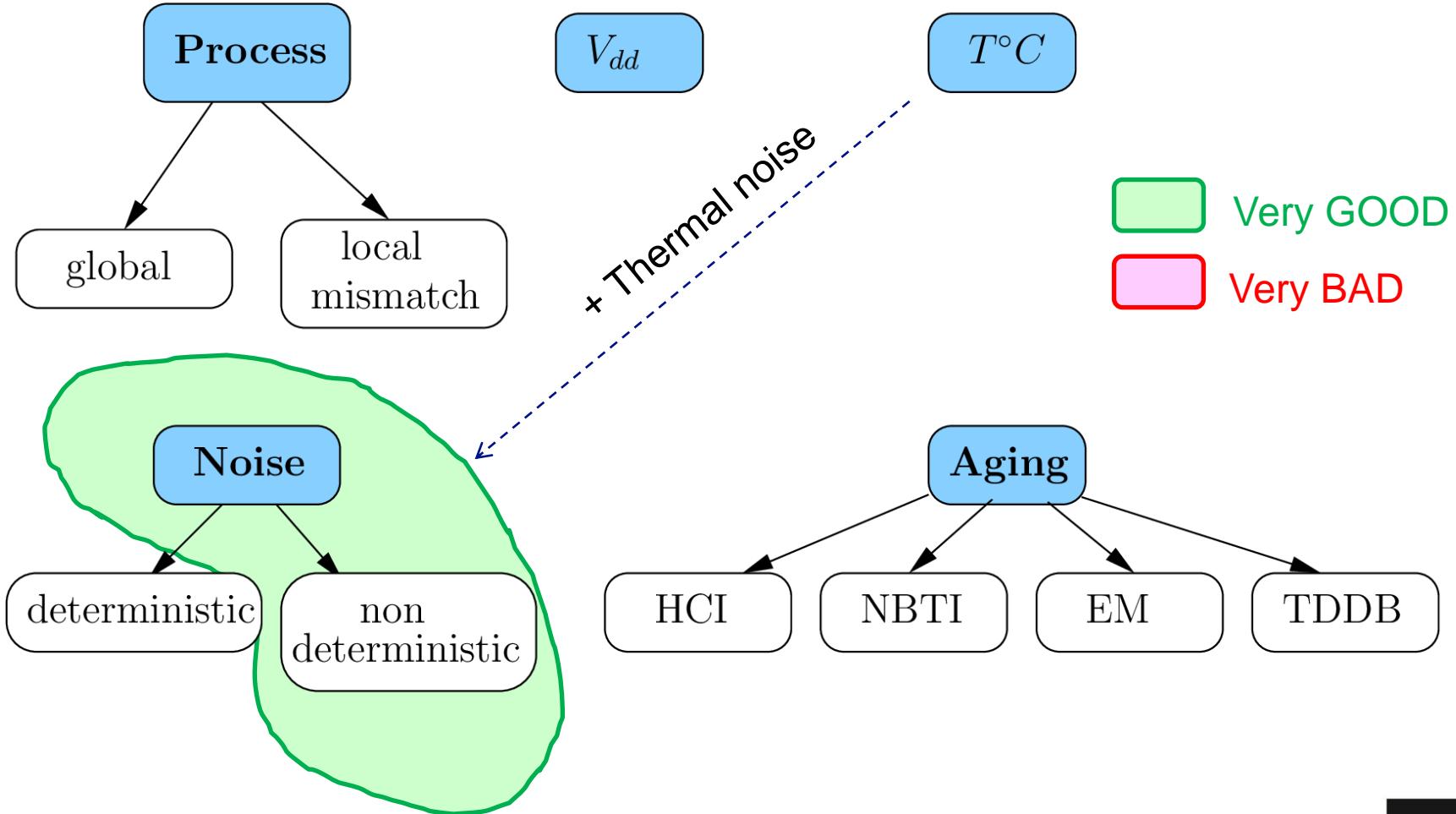


Source of attacks

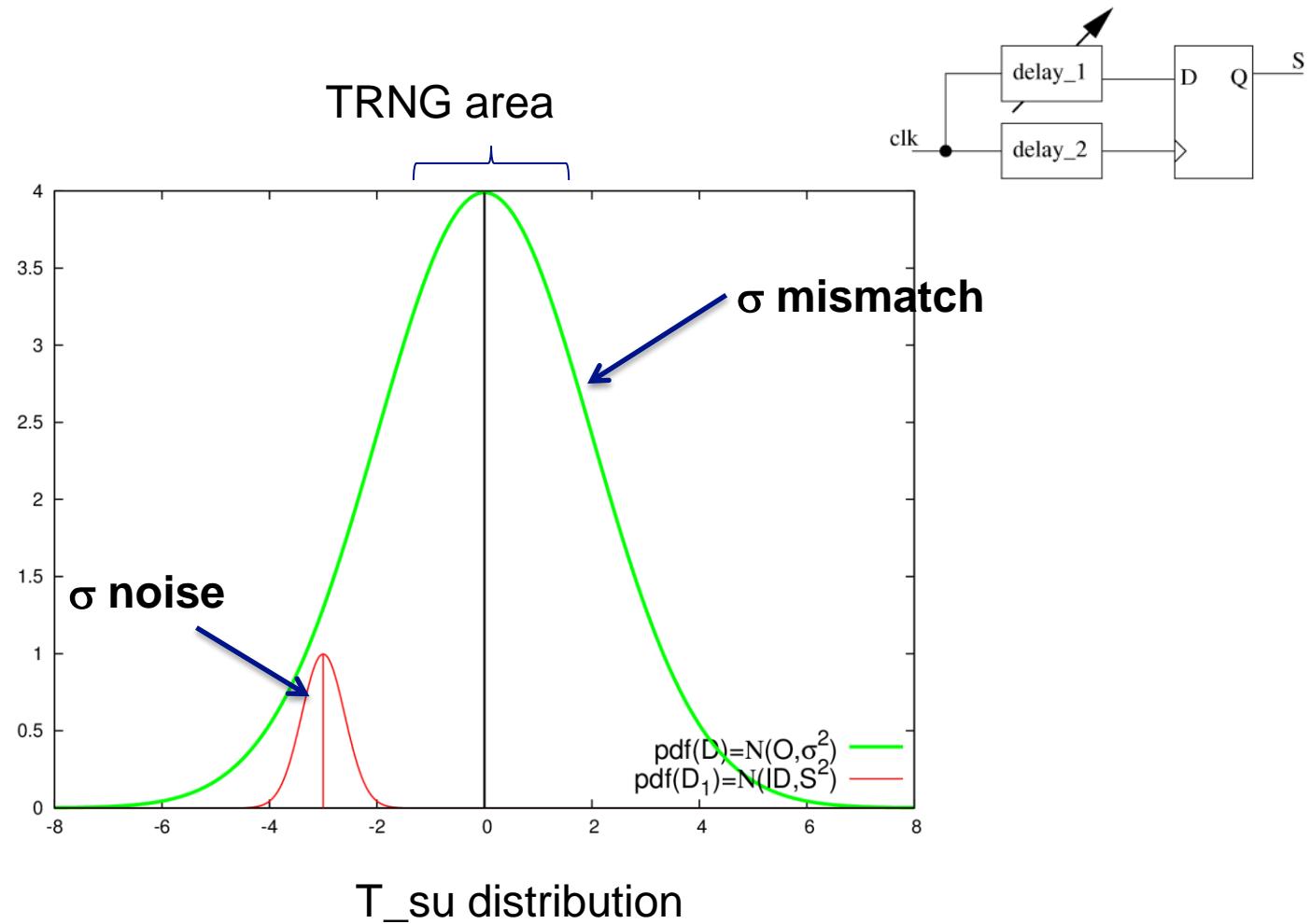
Ideally TRNG should be:

- undeterministic (temporal dependance)
- uncorrelated (spatial dependance)

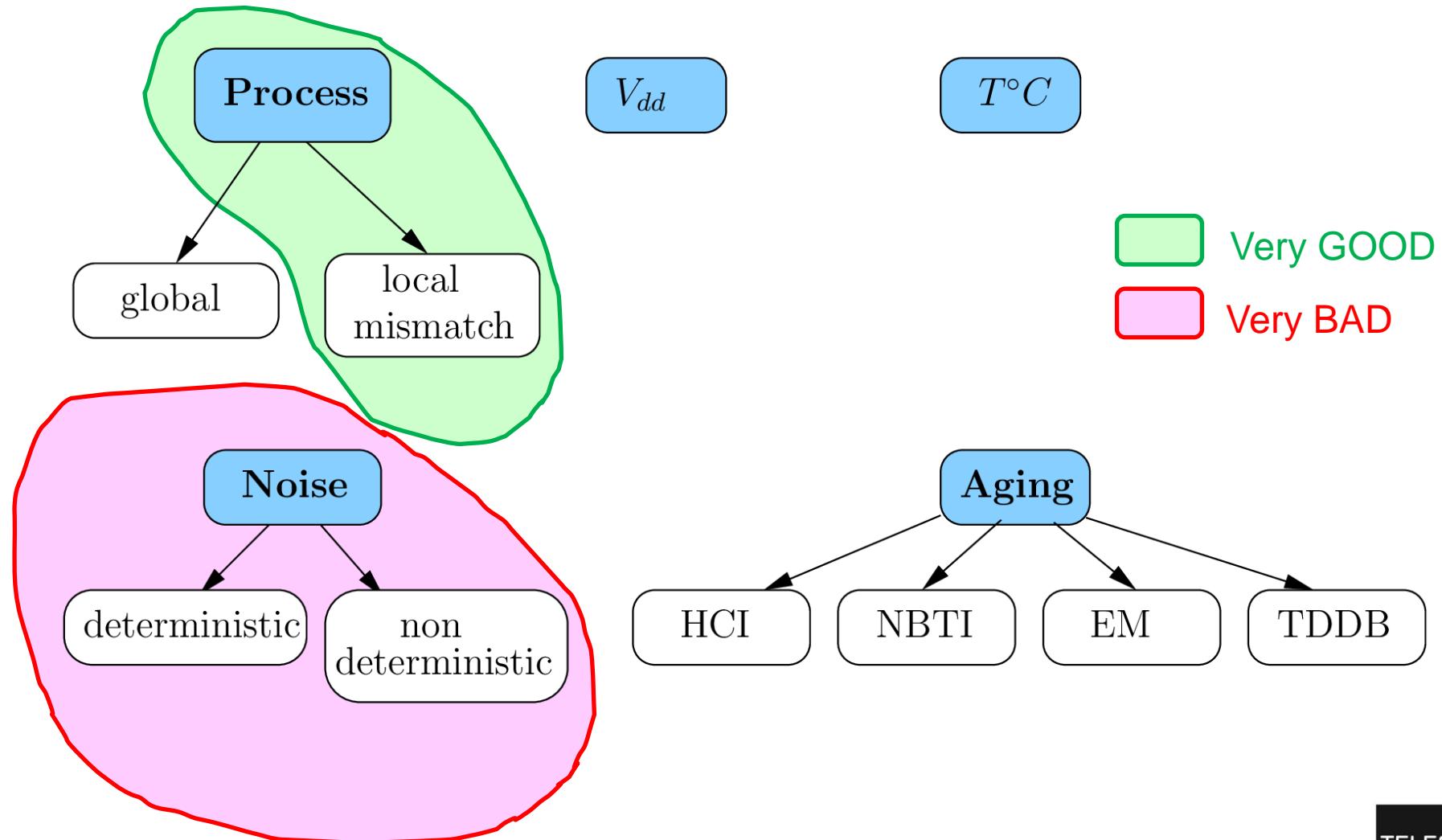
Variability impact for TRNG



Example: TRNG based on metastability

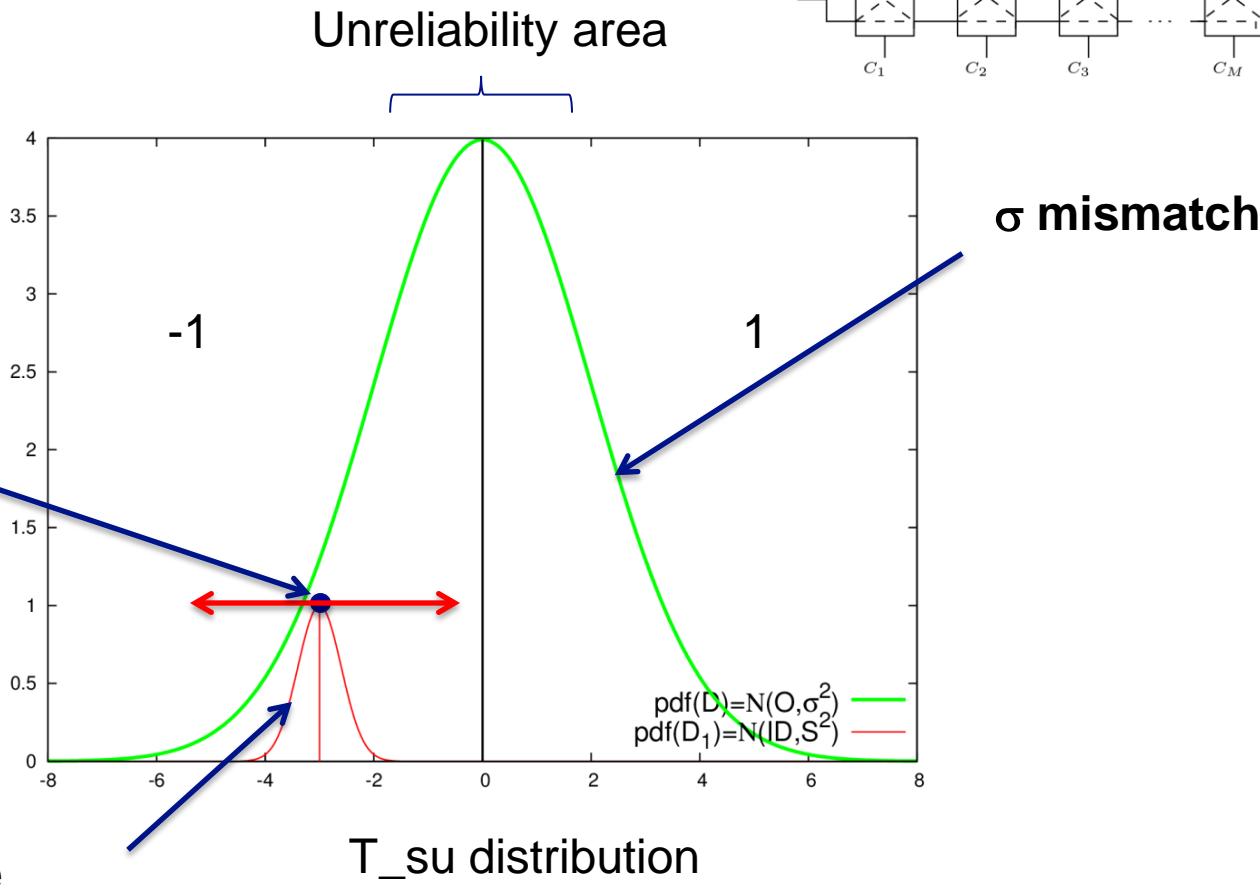


Variability impact for PUF



Example: Delay PUF

Impact of T°C,
Vdd, aging

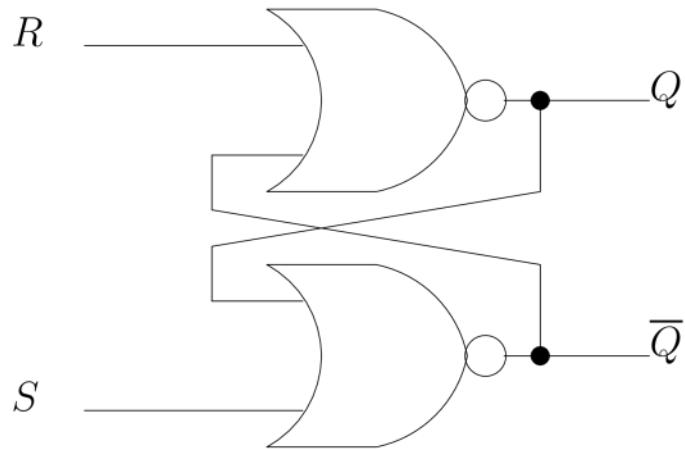




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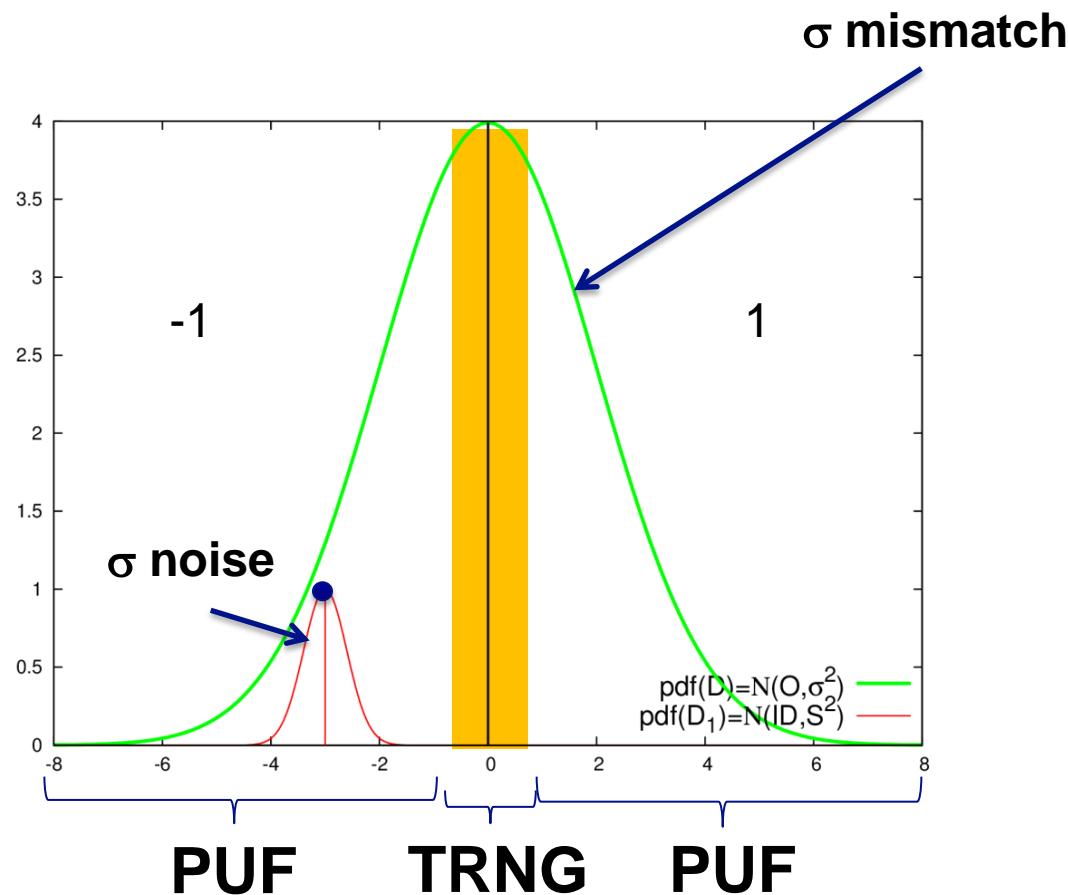
Basic element: RS latch



When R and S goes '1' to '0':

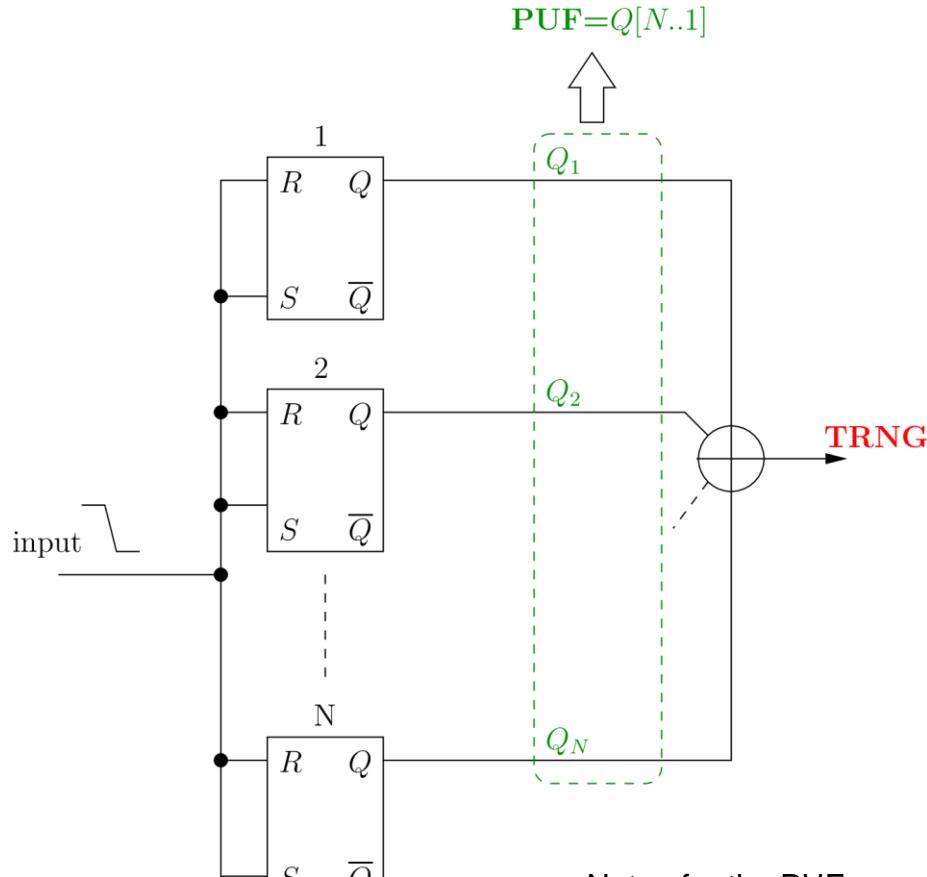
- **Metastable** state which converges toward a stable state.
- The stable state depends on:
 - noise => **TRNG**(Open Loop TRNG,...)
 - mismatch => **PUF** (latch PUF, TERO PUF,...)

RS latch: either TRNG or PUF



T_{su} distribution

PUF/TRNG architecture



Note : for the PUF a controlled delay line is necessary to detect unreliable RS latches

TRNG Statistical model

- First define the required entropy $H \Rightarrow P_H$
- Then compute the probability to get a good circuit with 1 RS latch
 - $P_{\text{ref}} = \text{erf}(\text{erf}^{-1}(2.P_H - 1) \sigma \text{ noise} / \sigma \text{ mismatch})$
- Then deduce the probability to get a good circuit with N elements
 - Pr (required entropy with N RS)
 $= 1 - (1 - P_{\text{ref}})^N$
 - Pr (required entropy with N RS and correlated noise)
 $= (1 - (1 - P_{\text{ref}})^N)^\alpha$ 

Note: The correlated noise corresponds to a shift of all the t_{su} distribution

PUF Statistical model

- First, define the unreliable area (or noise margin = $W \sigma$ noise) , in the center of the t-su distribution
- Then, compute the probability to get a reliable PUF

$$P_{\text{rel}} = 1 - \operatorname{erf} \left(\frac{\frac{W}{\sqrt{2}} - \sigma_{\text{noise}}}{\sigma_{\text{mismatch}}} \right)$$

- Then, compute the probability to get at least L reliable bits among N

$$\Pr_{\text{bits}}(L_{\text{reliable}}) = \beta(\Pr_{\text{rel}}; L, N - L + 1)$$



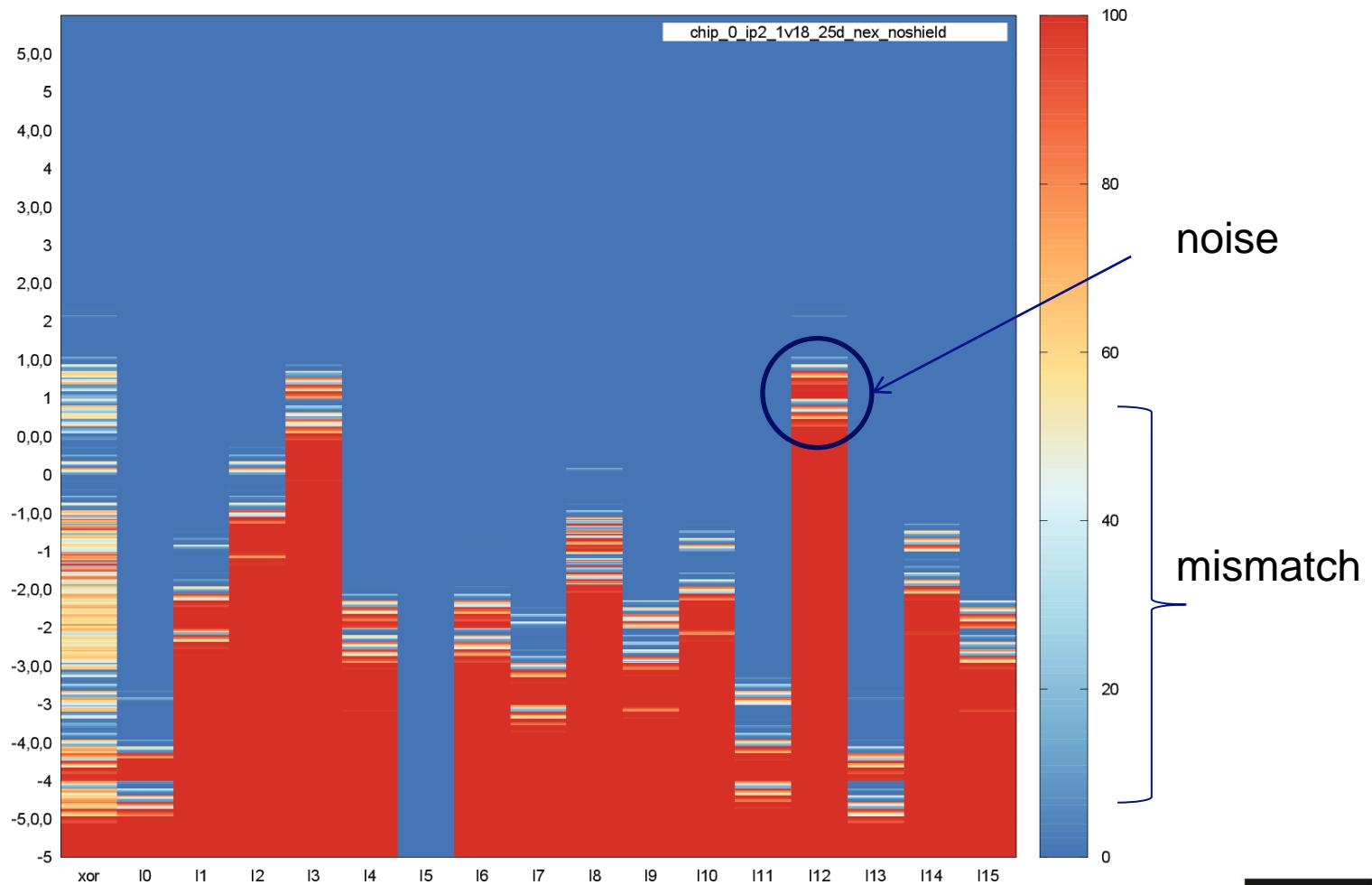
Uncomplete Beta function
= cumulative distribution of a binomial law



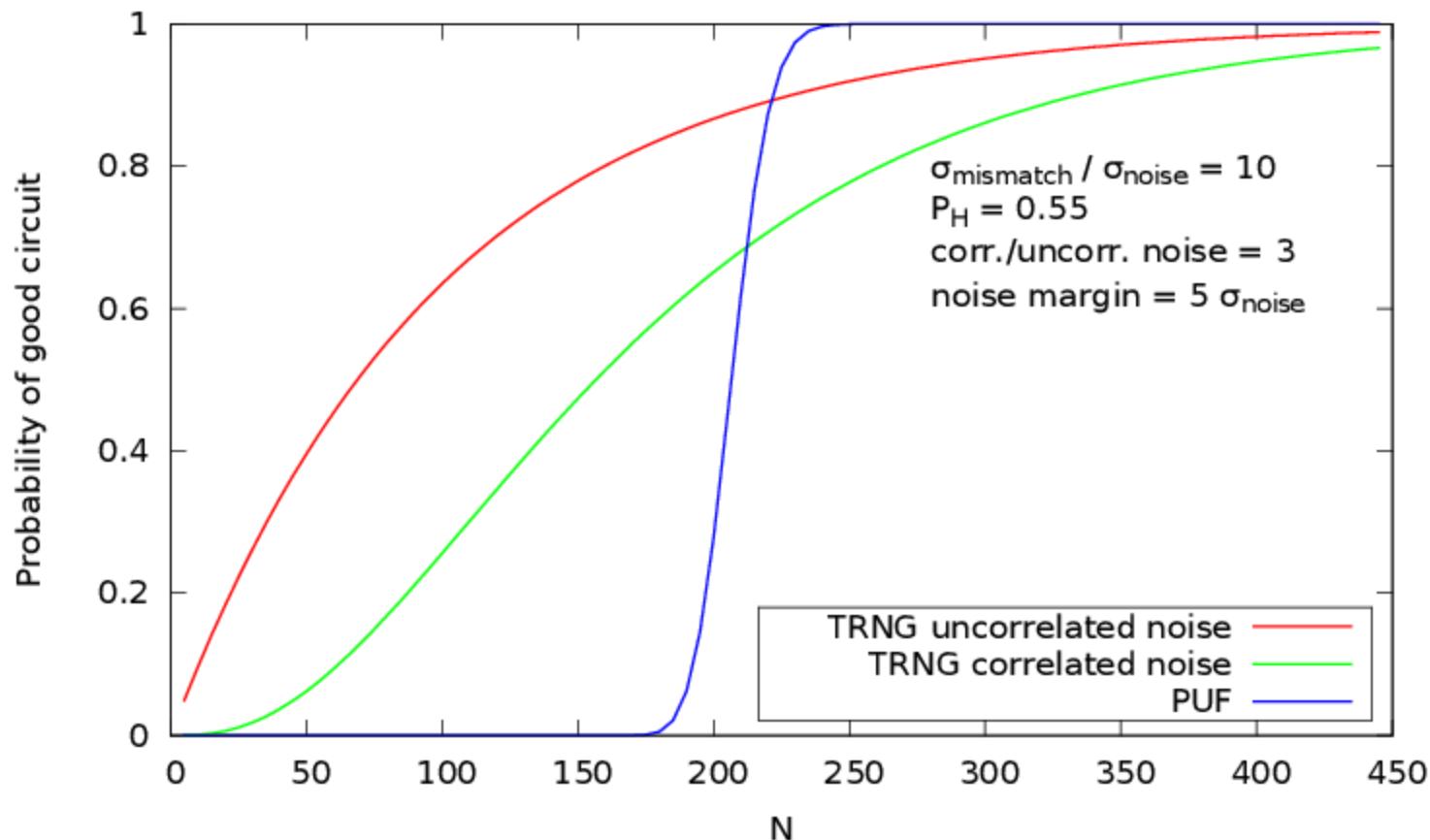
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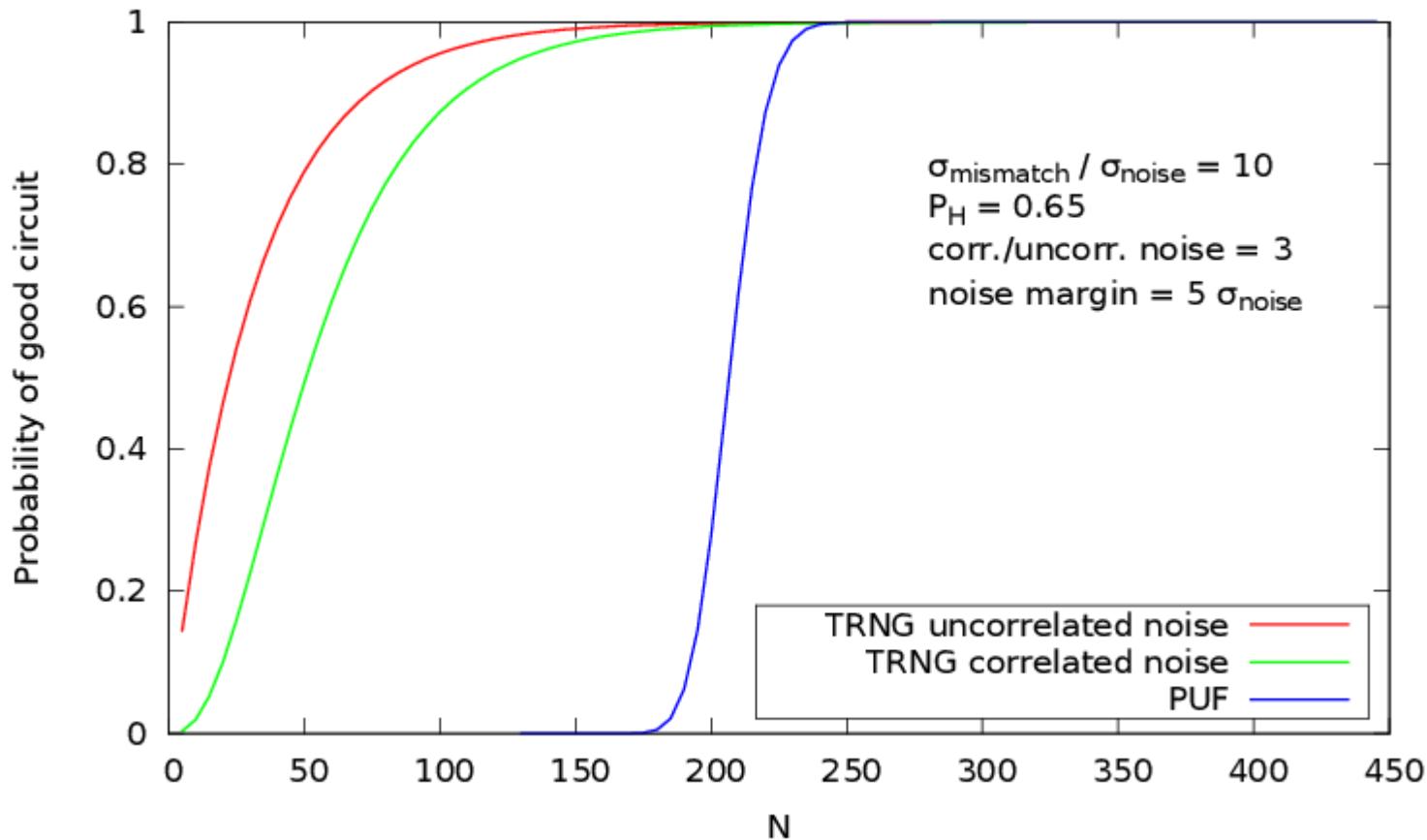
Results with 16 latches in 65nm technology



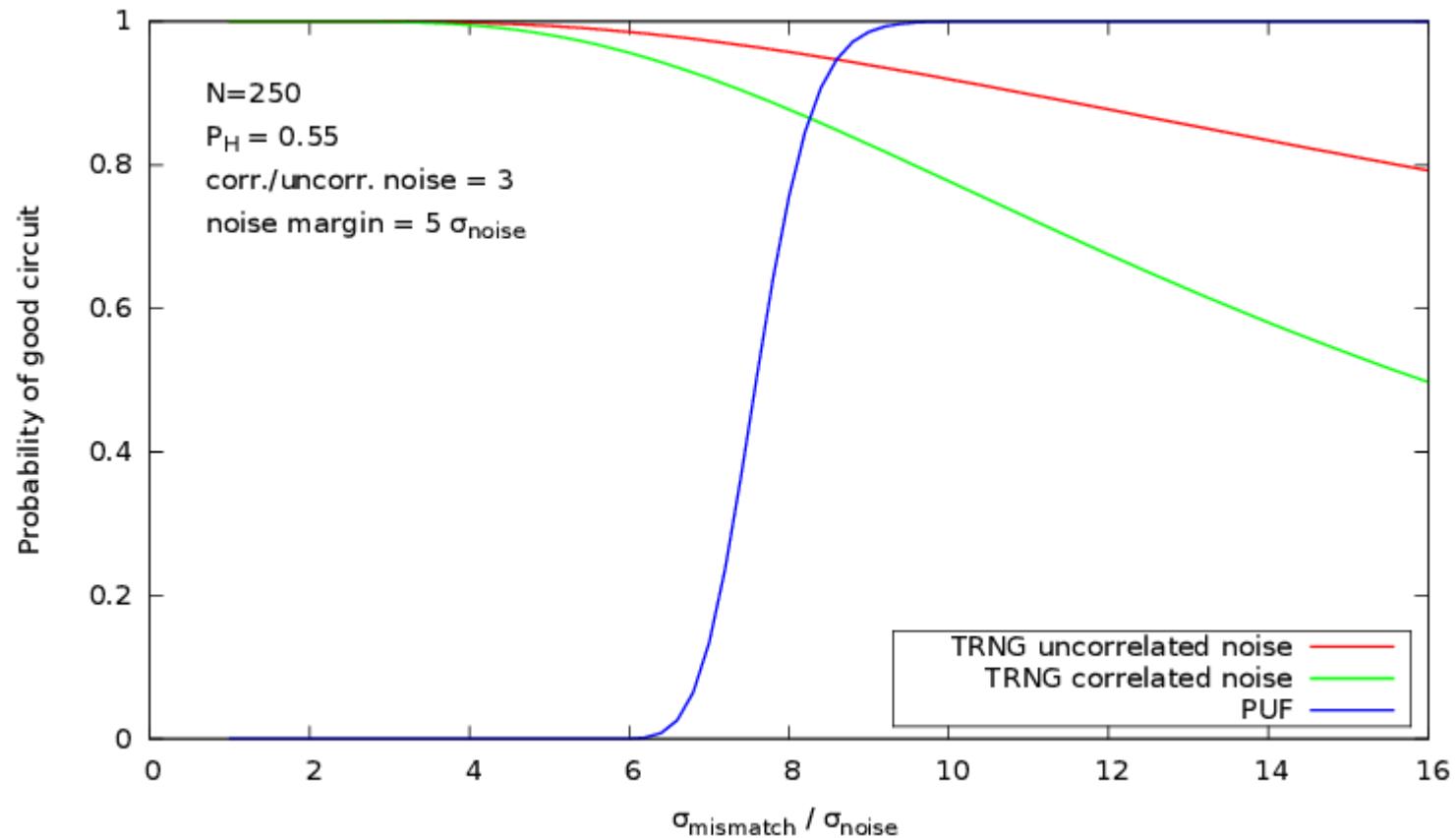
Impact of N with high entropy required



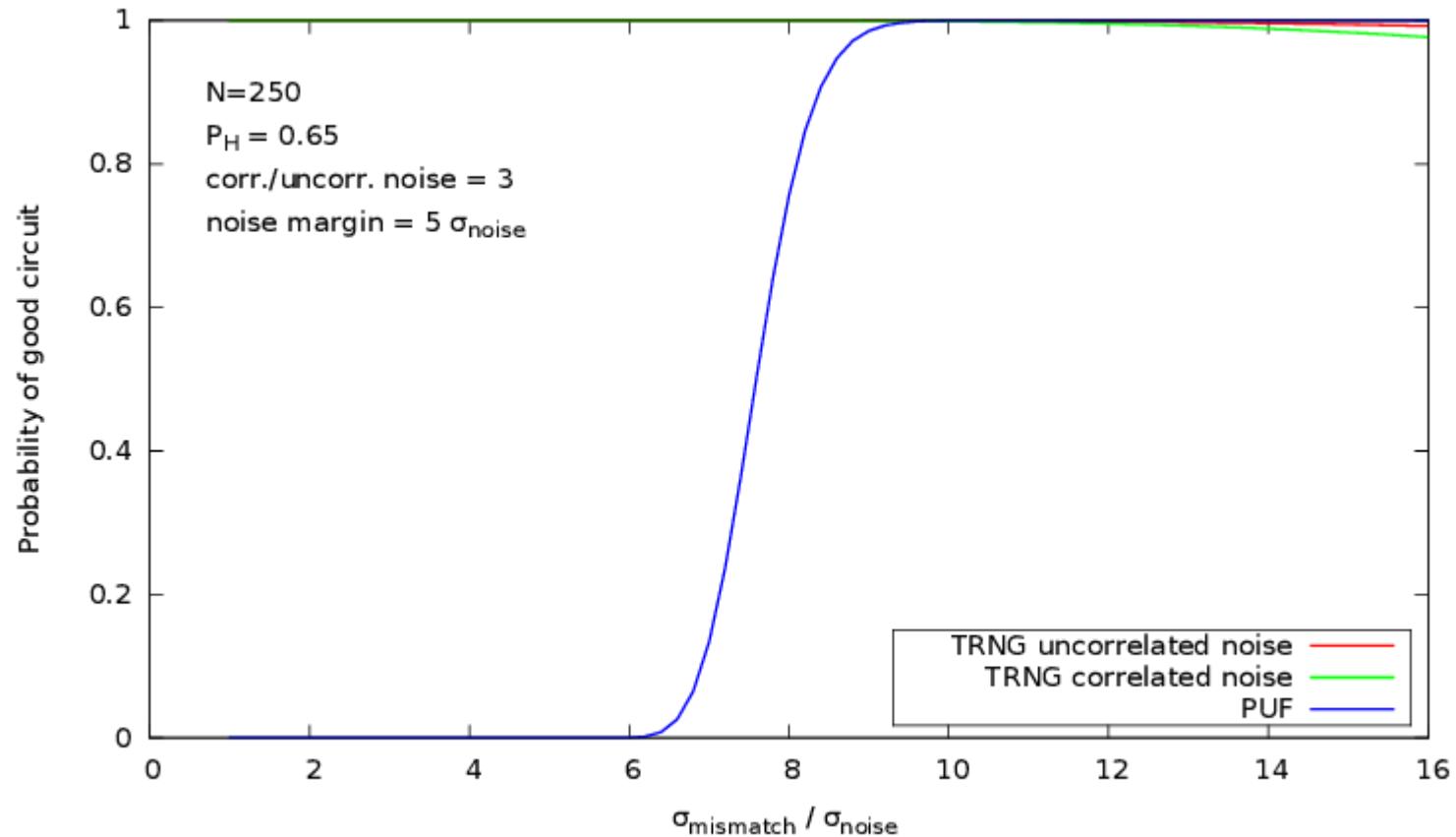
Impact of N with medium entropy required



Impact of $\sigma_{\text{mismatch}} / \sigma_{\text{noise}}$, high entropy required



Impact of $\sigma_{\text{mismatch}} / \sigma_{\text{noise}}$ medium entropy required





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Conclusions

- A TRNG/PUF can be obtained from a set of many RS latches
 - Exploits noise when T_{su} near 0
 - Exploits mismatch when T_{su} great
- Statistical models depend on:
 - σ mismatch/ σ noise
 - N
 - Required entropy for TRNG
 - Correlated noise for TRNG
 - Noise margin for PUF
- N can be low
 - by further post processing to enhance the entropy:
 - XORs, von neumann, compression,...